

2SD1847

Silicon NPN Triple-Diffused Planar Type

Horizontal Deflection Output

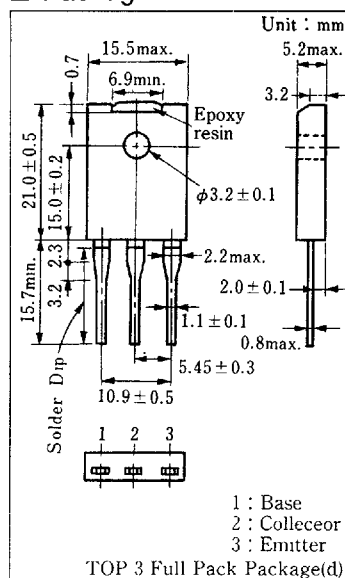
■ Features

- Damper diode built-in
- Minimizes external component counts and simplifies circuitry
- High breakdown voltage, high reliability
- High speed switching
- Wide area of safety operation (ASO)
- "Full Pack" package for simplified mounting on a heat sink with one screw

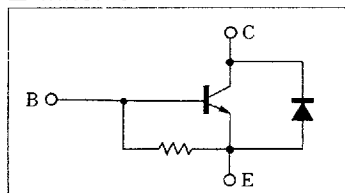
■ Absolute Maximum Ratings (Tc=25°C)

Item	Symbol	Value	Unit
Collector-base voltage	V_{CB0}	1500	V
Collector-emitter voltage	V_{CES}	1500	V
	V_{CEO}	700	V
Emitter-base voltage	V_{EBO}	7	V
Peak collector current	I_{CP}	15	A
Collector current	I_C	5	A
Base current	I_B	2	A
Collector power dissipation	$T_C = 25^\circ\text{C}$	P_C	W
	$T_a = 25^\circ\text{C}$	3	
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 ~ +150	°C

■ Package Dimensions

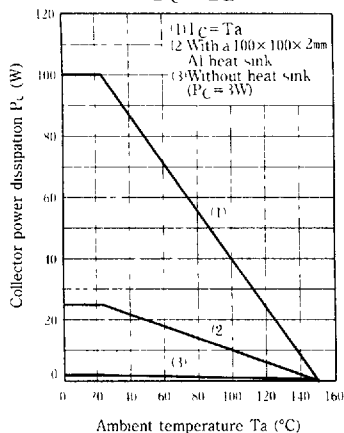
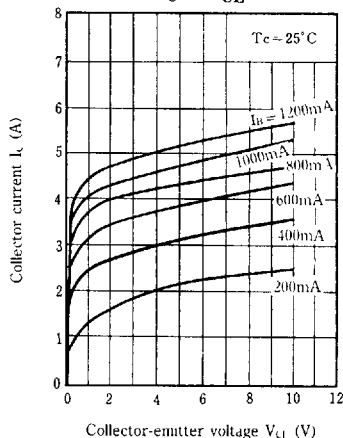
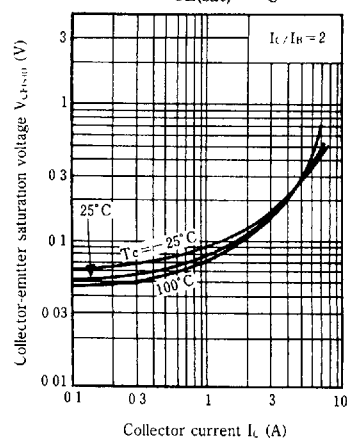
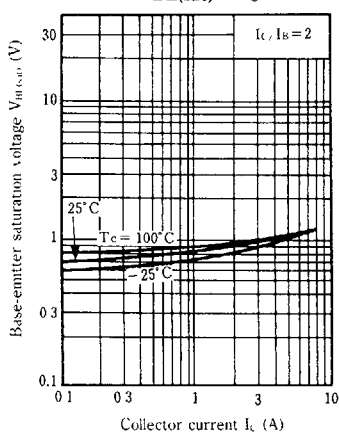
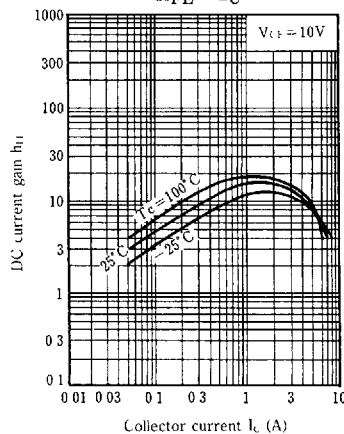


■ Inner Circuit

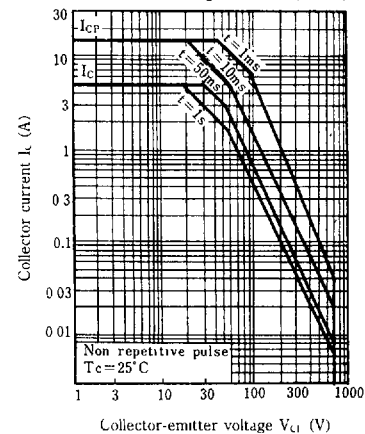


■ Electrical Characteristics (Tc=25°C)

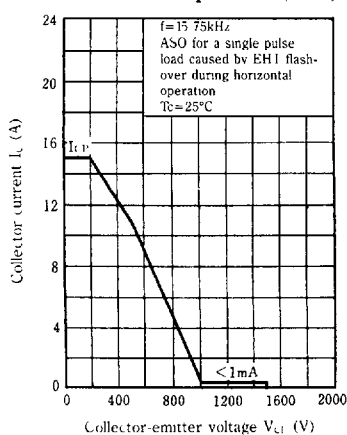
Item	Symbol	Condition	min.	typ.	max.	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = 750\text{V}, I_E = 0$			10	μA
		$V_{CB} = 1500\text{V}, I_E = 0$			1	mA
Emitter-base voltage	V_{EBO}	$I_E = 500\text{mA}, I_C = 0$	7			V
DC current gain	h_{FE}	$V_{CE} = 5\text{V}, I_C = 1\text{A}$	5		25	
		$V_{CE} = 10\text{V}, I_C = 4\text{A}$	4			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 4\text{A}, I_B = 1\text{A}$			8	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = 4\text{A}, I_B = 1\text{A}$			1.5	V
Transition frequency	f_T	$V_{CE} = 10\text{V}, I_C = 1\text{A}, f = 0.5\text{MHz}$		2		MHz
Storage time (L load)	t_{stg}	$I_C = 4\text{A}, I_{B1} = 1\text{A}$			9	μs
Collector current fall time (L load)	t_f	$I_{B2} = -1\text{A}, L_{leak} = 5\mu\text{H}$			0.8	μs
Storage time (R load)	t_{stg}	$I_C = 4\text{A}, I_{B1} = 1\text{A}$		1.5		μs
Collector current fall time (R load)	t_f	$I_{B2} = -2\text{A}, V_{CC} = 200\text{V}$		0.2		μs
Diode forward voltage	V_F	$I_C = -5\text{A}, I_B = 0$			2.3	V

$P_C - T_a$  $I_C - V_{CE}$  $V_{CE(sat)} - I_C$  $V_{BE(sat)} - I_C$  $h_{FE} - I_C$ 

Area of safe operation (ASO)



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 $R_{th(t)} - t$ 